

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









High voltage fast-switching NPN Power Transistor

General features

- NPN Transistor
- High voltage capability
- Low spread of dynamic parameters
- Minimum lot-to-lot spread for reliable operation
- Very high switching speed
- Fully characterized at 125 °C
- In compliance with the 2002/93/EC European Directive

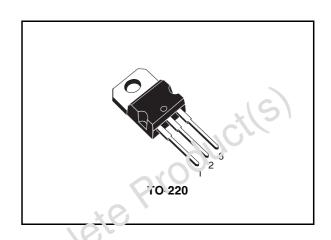


The device is manufactured using high voltage Multi-Epitaxial Planar technology for high switching speeds and medium voltage capability.

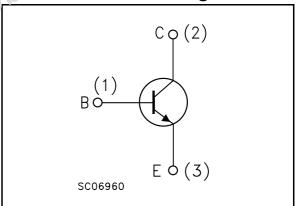
It uses a Cellular Emitter structure with planar edge termination to enhance switching speeds while maintaining the wide RBSOA.

Applications

- Electronic balla t for fluorescent lighting
- Dedicated for PFC solution in HF ballast halfbridge voitage ied



Internal schematic diagram



Order codes

Part Number	Marking	Package	Packing
BUL705	BUL705	TO-220	Tube

Contents

1	Electrical ratings 3
2	Electrical characteristics4
	2.1 Electrical characteristics (curves)
	2.2 Test circuits
3	Package mechanical data
4	Revision history
0050	Electrical characteristics

BUL705 Electrical ratings

1 Electrical ratings

Table 1. Absolute maximum rating

Symbol	Parameter	Value	Unit
V _{CES}	Collector-emitter voltage (V _{BE} = 0)	700	٧
V _{CEO}	Collector-emitter voltage (I _B = 0)	400	V
V _{EBO}	Emitter-base voltage (I _C = 0)	10	V
I _C	Collector current	5	Α
I _{CM}	Collector peak current (t _P < 5ms)	10	A
I _B	Base current	2	Α
I _{BM}	Base peak current (t _P < 5ms)	4	Α
P _{tot}	Total dissipation at T _c = 25°C	80	W
T _{stg}	Storage temperature	-65 to 150	°C
T _J	Max. operating junction temperature	150	°C

Table 2. Thermal data

	Symbol	Parameter		Value	Unit	
	R _{thj-case}	Thermal resistance junction-case	max	1.56	°C/W	
	R _{thj-amb}	Thermal resistance junction-amb	max	62.5	°C/W	
Obsole	te P	Kogir				

Electrical characteristics BUL705

2 Electrical characteristics

(T_{case} = 25°C unless otherwise specified)

Table 3. Electrical characteristics

Table 3.	Electrical characteristics					
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I _{CES}	Collector cut-off current (V _{BE} =-1.5V)	$V_{CE} = 700V$ $V_{CE} = 700V$ $T_{j} = 125$	5°C		100 500	μ Α μ Α
I _{CEO}	Collector cut-off current (I _B =0)	V _{CE} =400V			250	μА
V _{EBO}	Emitter-base voltage (I _C = 0)	I _E =10mA	10	111		V
V _{CEO(sus)} (1)	Collector-emitter sustaining voltage (I _B = 0)	I _C =100mA L =25n	nH 100	Ore		V
V _{CE(sat)} (1)	Collector-emitter saturation voltage	$I_{C} = 2A$ $I_{B} = \sqrt{4} \frac{4}{4}$ $I_{C} = 3A$ $I_{B} = 0.6A$ $I_{C} = 4A$ $I_{B} = 1A$			0.4 0.6 0.8	V V V
V _{BE(sat)} (1)	Base-emitter saturation voltage	I _C = 3A I _B = 0.4A I _B = 0.6A			1.1 1.2	V V
h _{FE}	DC current nan	I _C =10mA V _{CE} =5V I _C =2A V _{CE} =5V			32	
ts	Resistive load Storage time	$V_{CC} = 250V$ $I_{C} = 2A$ $I_{B1} = -I_{B2} = 0.4A$ (see fig.12)	2.4		3.5	μs
t _s	Inductive load Storage time Fall time	I_{C} =2A I_{B1} =0.4 $V_{BE(off)}$ =-5V R_{BB} =0.9 V_{clamp} =250V L =200 μ (see fig.13)	Ω	0.7 50	1.4 100	μs ns
t _s	Inductive load Storage time Fall time	$\begin{split} & I_{C} = 2A & I_{B1} = 0.4 \\ & V_{BE(off)} = -5V & R_{BB} = 0.9 \\ & V_{clamp} = 250V & L = 200 \\ & T_{j} = 125^{\circ}C & (see fig) \end{split}$	Ω ιH	1 75		μs ns

Note (1) Pulsed duration = 300 μ s, duty cycle \leq 1.5%

2.1 Electrical characteristics (curves)

Figure 1. Safe operating area

Figure 2. Derating Curve

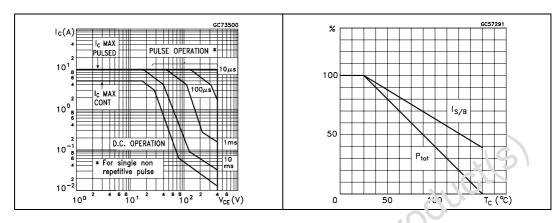


Figure 3. DC current gain

Figure 4. DC current gain

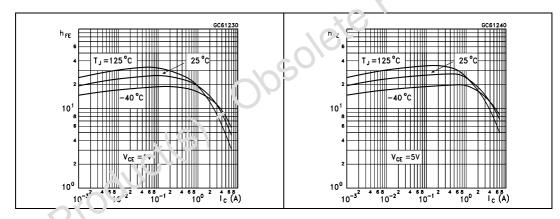
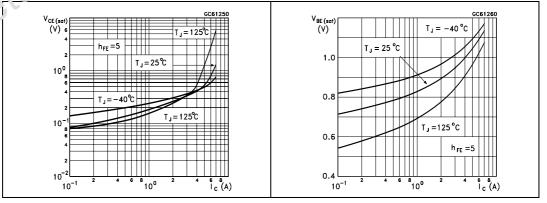


Figure 5. Collector-emitter saturation voltage

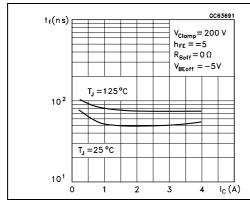
Figure 6. Base-emitter saturation voltage

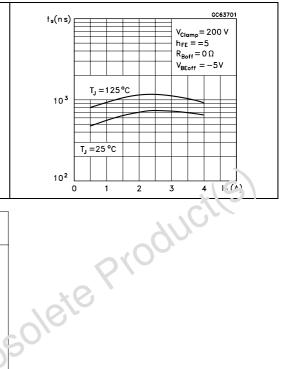


Electrical characteristics BUL705

Figure 7. Inductive load fall time

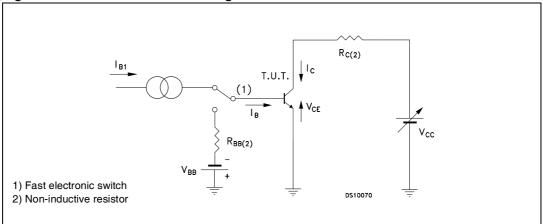
Figure 8. Inductive load storage time





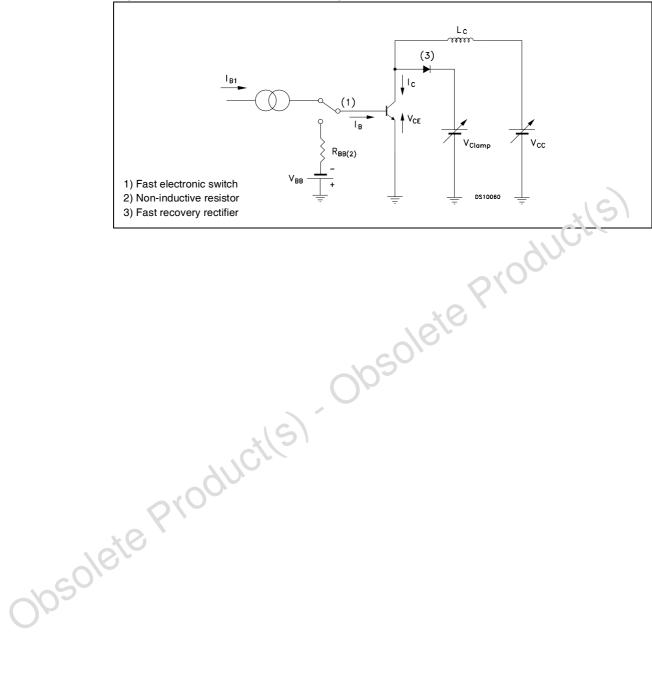
2.2 Test circuits

igure 10. Resistive load switching test circuit



BUL705 Electrical characteristics

Figure 11. Inductive load switching test circuit



577

3 Package mechanical data

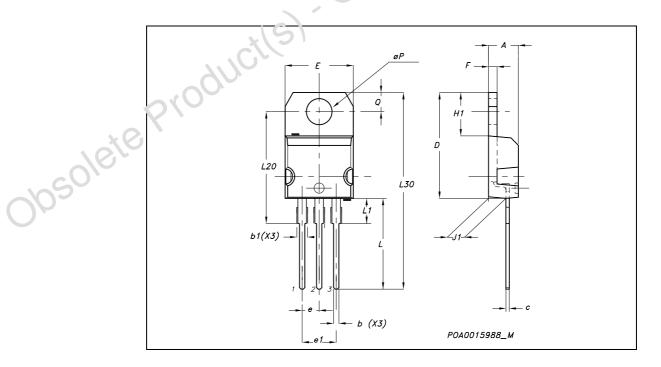
In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

Obsolete Producits) - Obsolete Producits)

577

TO-220 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
Α	4.40		4.60	0.173		0.181
b	0.61		0.88	0.024		0.034
b1	1.15		1.70	0.045		0.066
С	0.49		0.70	0.019		0.027
D	15.25		15.75	0.60		0.520
Е	10		10.40	0.393		0.40°
е	2.40		2.70	0.094	. (0.106
e1	4.95		5.15	0.194		0.202
F	1.23		1.32	0.048		0.052
H1	6.20		6.60	0.244		0.256
J1	2.40		2.72	0.061		0.107
L	13		14	0.511		0.551
L1	3.50		3.93	J.137		0.154
L20		16.40		P	0.645	
L30		28.90			1.137	
øΡ	3.75		2 85	0.147		0.151
Q	2.65		∠.95	0.104		0.116



Revision history BUL705

4 Revision history

Table 4. Revision history

Date	Revision	Changes
22-May-2006	1	Initial release.

Obsolete Product(s). Obsolete Product(s)

Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and ser rices described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and Rervices described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property lights is granted under this document. If any part of this document refers to any third party products or services it shall not be defined a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered a license grant by ST for the use of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERIC. AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USF AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, F'I NEGS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINCEME IT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN MIRITING BY AN AUTHORIZE REPRESENTATIVE OF ST, ST PRODUCTS ARE NOT DESIGNED, AUTHORIZED OR WARPALTICD FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OF GYSTEMS, WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE.

Resale c'. 21 products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any l'ac'inty of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2006 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

